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NOMENCLATURE

PVG	Photovoltaic Generator
a-Si:H/c-Si	Amorphous/crystalline silicon
I – V	Current vs Voltage Characteristic
P – V	Power vs Voltage Characteristic
TCO	Transparent, Conductive layer
TiO_2	Dioxyde de titane
Al_2O_3	Alumine
Si	Silicon
SHJ	Silicon Hetero-Junction